

Application
Number

SEARCH

IDS Flag Clearance for Application 10809853

IDS
Information

Content	Mailroom Date	Entry Number	IDS Review	Reviewer
M844	03-24-2004	10	<input checked="" type="checkbox"/>	08-11-2005 00:56:55 IDS CONV
M844	06-08-2004	14	<input checked="" type="checkbox"/>	08-11-2005 00:56:55 IDS CONV
M844	10-12-2004	16	<input checked="" type="checkbox"/>	08-11-2005 00:56:55 IDS CONV
M844	01-10-2005	18	<input checked="" type="checkbox"/>	08-11-2005 00:56:55 IDS CONV

UPDATE

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L5	46	polysilicon same etch\$3 with (plasma wet) same (side wall) with (inclin\$3 taper\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/01 10:45
L6	31	polysilicon same etch\$3 with (plasma wet) same (side wall) with angle	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/01 10:51
L7	1210	polysilicon with width same etch\$3 and (plasma wet)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/01 10:52
L8	330	polysilicon with width same etch\$3 same (plasma wet)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/01 11:45
L12	404	polysilicon with (taper decline angle) same etch\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/01 11:54
L13	359	intel.as. and polysilicon and etch\$3 and (inclin\$3 taper\$3 width)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/01 11:56
L14	95	intel.as. and polysilicon same (inclin\$3 taper\$3 width) and etch	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/01 11:57